

# Basics of Analog Multiplexers 2

TIPL 2602

TI Precision Labs – Op Amps

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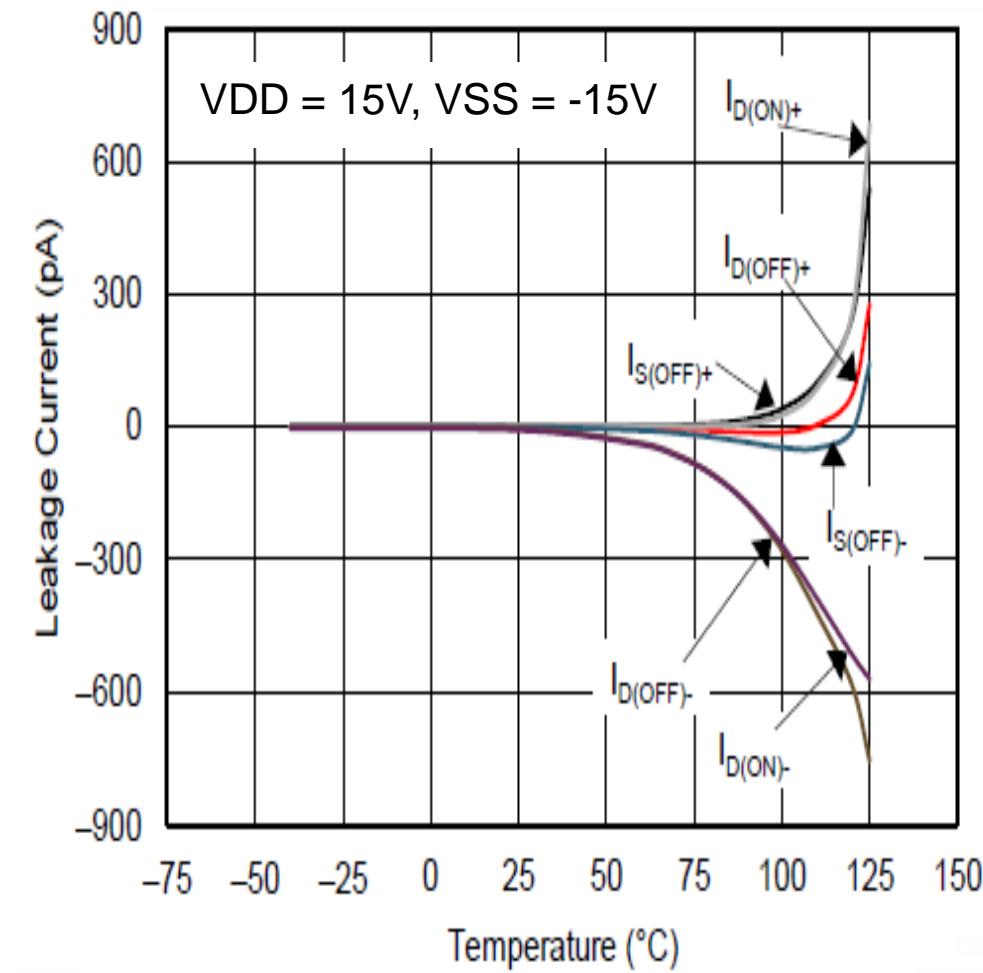
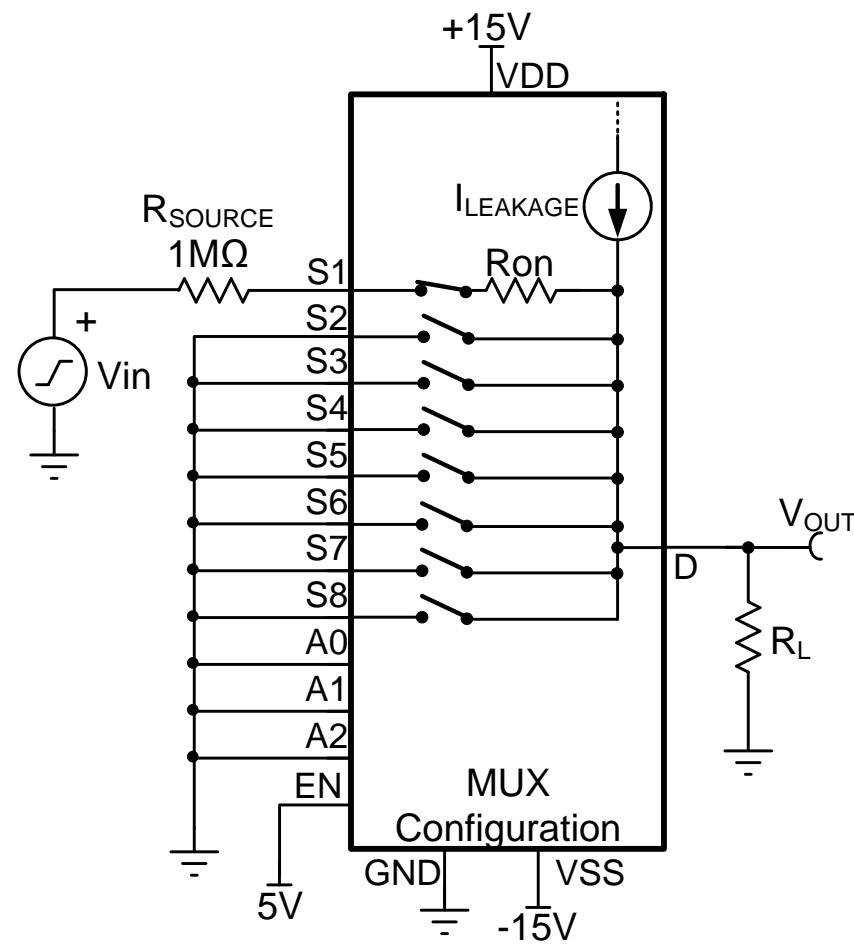


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# Analog Multiplexer Parameters Summary

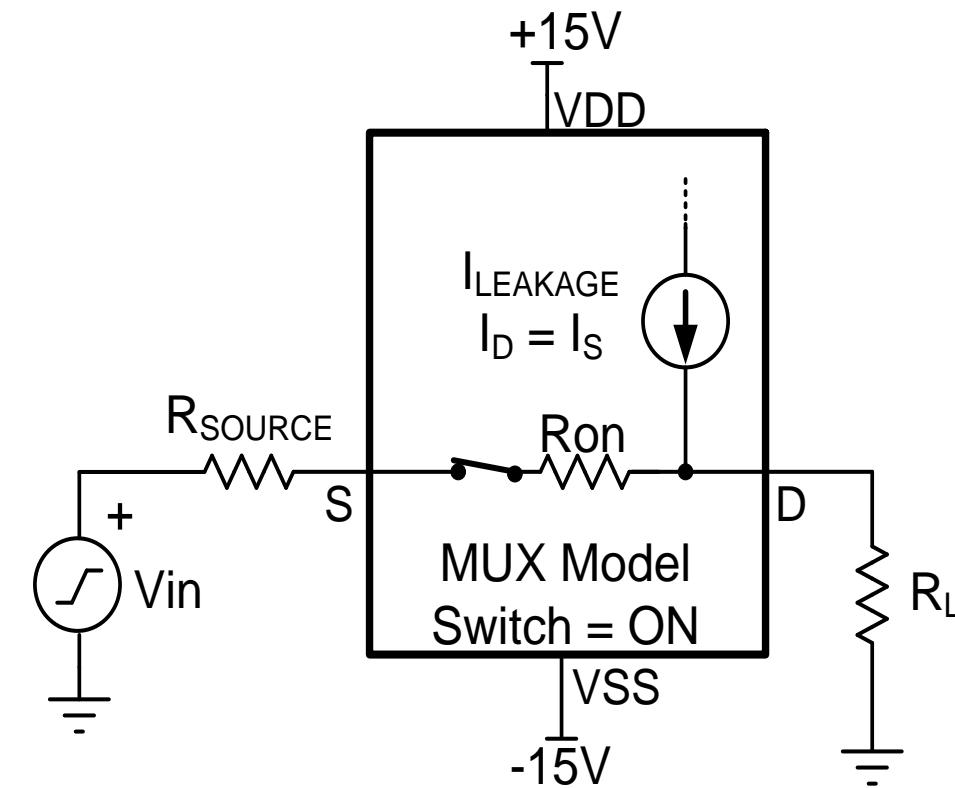
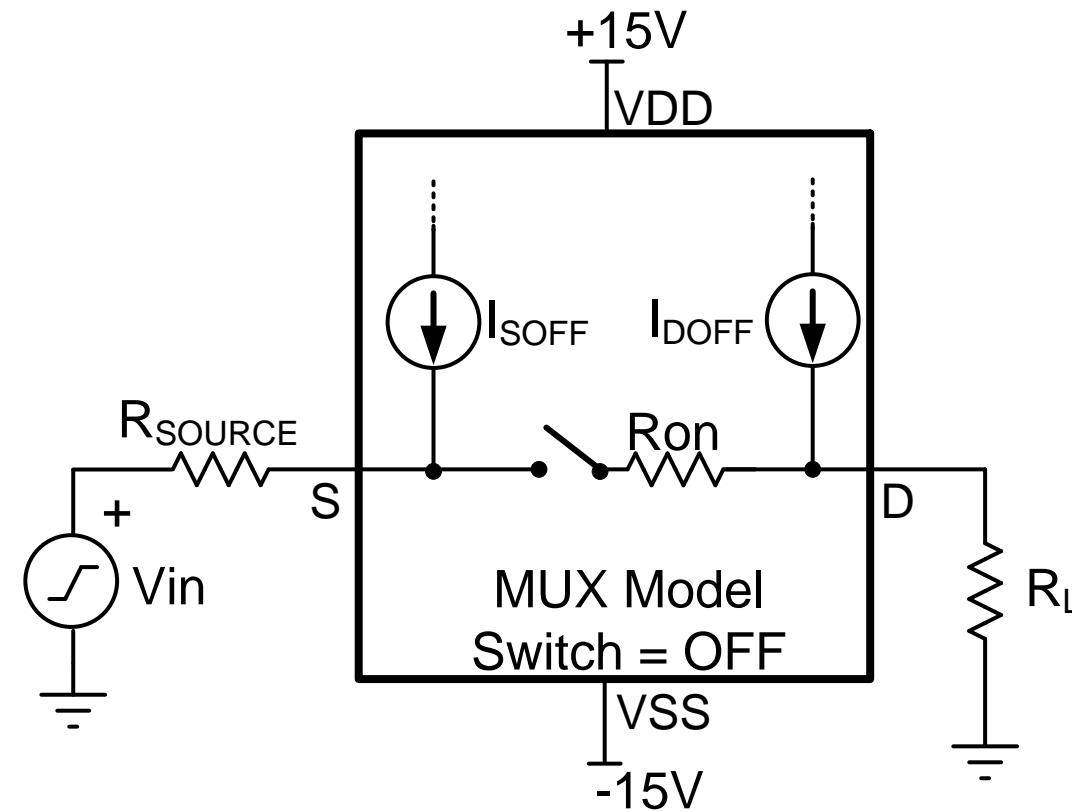
- Part 1: Understanding Performance parameters of Multiplexer
  - 1) Leakage Current
    - Types of Leakage Current
    - Offset issues Related to Leakage Current
  - 2) Charge Injection
    - Understanding Charge Injection Phenomenon
    - Effect of Charge Injection on Multiplexer Output Voltage Error
- Goals:
  - 1. To understand performance parameters of multiplexers
  - 2. Understand their importance while designing data acquisition system

# Leakage Current



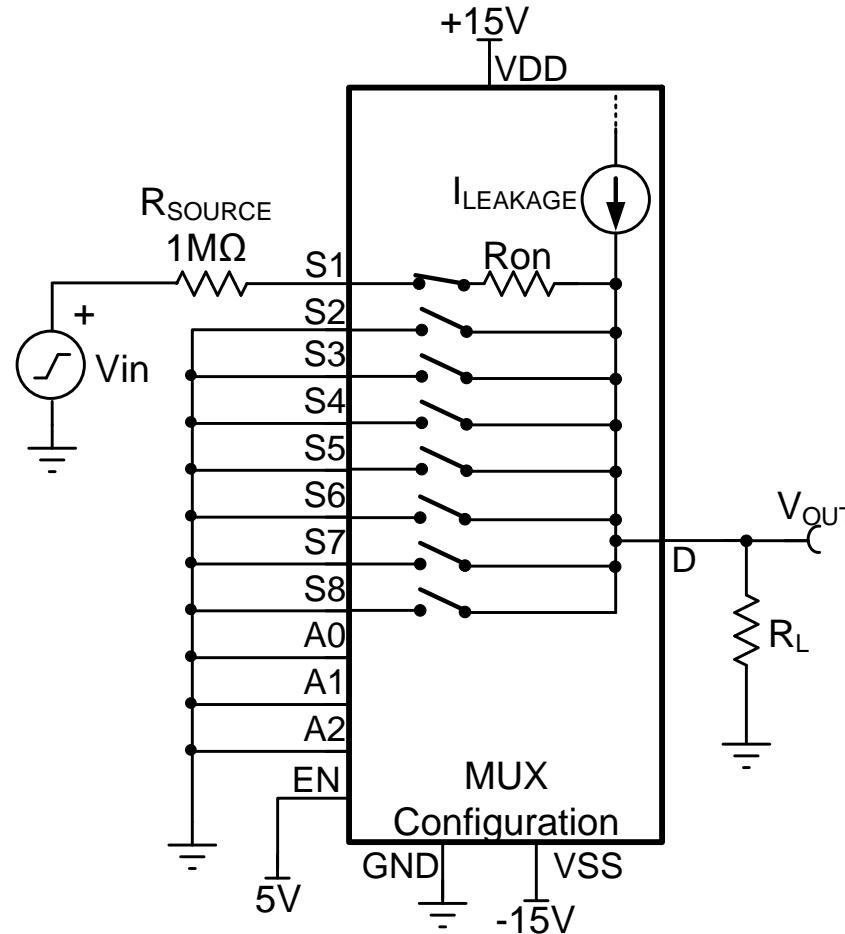
- **Leakage Current:** Current flowing out Source (S) and Drain (D) pins when MUX switch is ON or OFF
- **Switch = OFF:** Leakage current flows out Source pin and Drain pin,  $I_{S(OFF)}$  and  $I_{D(OFF)}$
- **Switch = ON:** Approximate leakage current out Source and Drain pin is  $I_{S(ON)} = I_{D(ON)}$

# Leakage Current



- **Switch = OFF:**  $I_{S(OFF)}$  flows through  $R_{SOURCE}$  and  $I_{D(OFF)}$  flows through  $R_L$
- **Switch = ON:** Error introduced by leakage current:  $V_{ERROR} = (R_{ON} + R_{SOURCE}) \times I_{D(ON)}$

# Offset Error Introduced by Leakage Current



## 18-bit System Example Calculation

$$V_{\text{ref}} = 5V$$

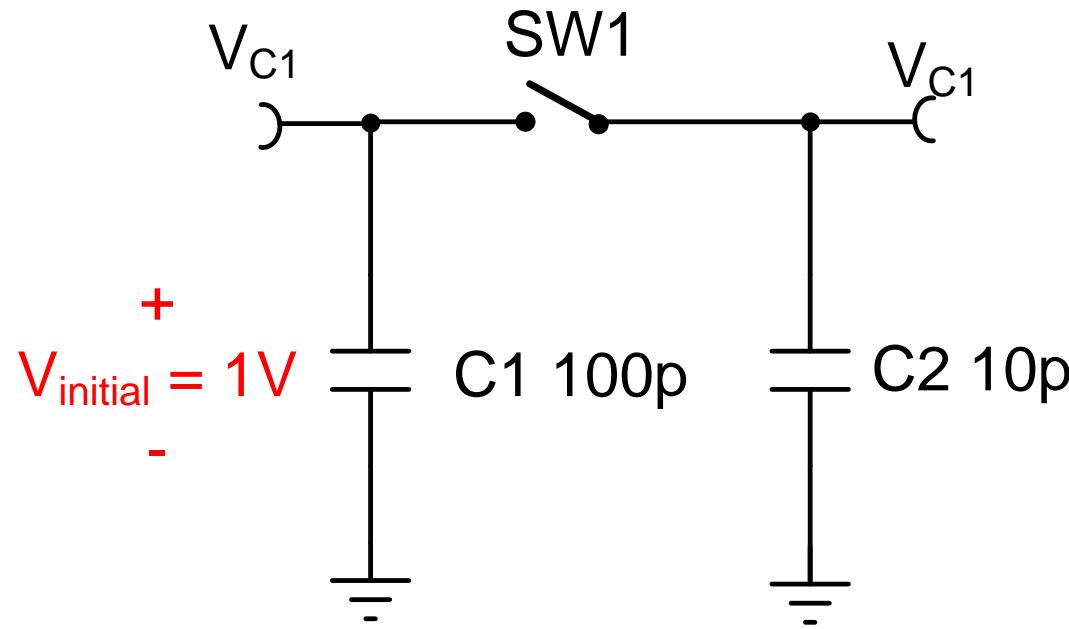
$$V_{\text{LSB}} = \frac{5V}{2^{18}} = 19.073\mu V$$

$$\text{OffsetError(V)} = I_{\text{LEAKAGE}} \cdot R_{\text{SOURCE}} = (100\text{pA})(1\text{M}\Omega) = 100\mu V$$

$$\text{OffsetError(Bits)} = \frac{\text{OffsetError(V)}}{V_{\text{LSB}}} = \frac{100\mu V}{19.073\mu V} = 5.24 \text{ codes}$$

Multiplexer Examples	Multiplexer leakage current (25°C/85°C)	Offset error (25°C/85°C) (I <sub>LEAKAGE</sub> x R <sub>Source</sub> )	Offset Error 18 bit System (in bits)
MUX1 (Low Leakage)	10pA/50pA	10μV/50μV	0.52 / 2.62
MUX2 (High Leakage)	100pA/500pA	100μV/500μV	5.24 / 26.22

# Review: Charge Equation



Definition

$Q$  = Charge in Coulombs

$C$  = Capacitance in Farads

$V$  = Voltage in Volts

Charge of C1,  
Assuming initial 1V

Close switch

New Voltage after charge  
redistribution

## Charge Equation Example

$$Q = C \cdot V$$

$$Q = C_1 \cdot V_1 = (100\text{pF}) \cdot (1\text{V}) = 100\text{pC}$$

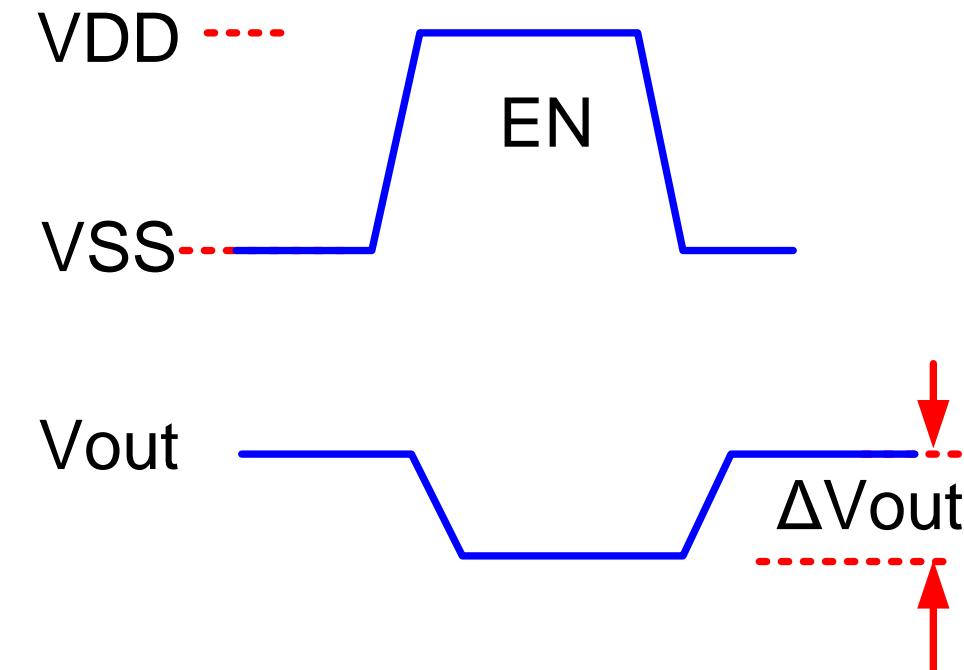
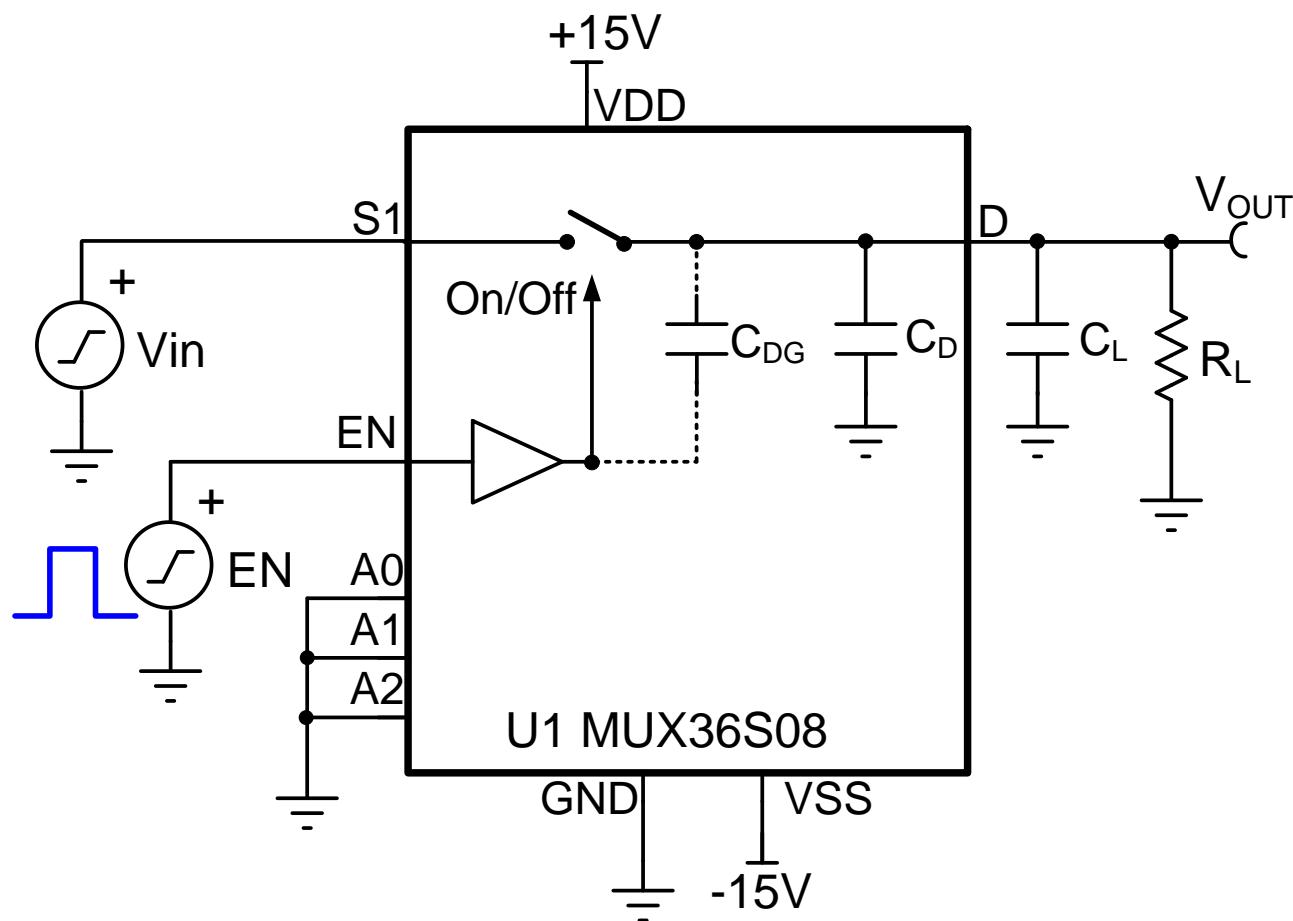
$$C_{\text{total}} = C_1 + C_2 = 110\text{pF}$$

$$V_{\text{final}} = \frac{Q}{C_{\text{total}}} = \frac{100\text{pC}}{110\text{pF}} = 0.909\text{V}$$



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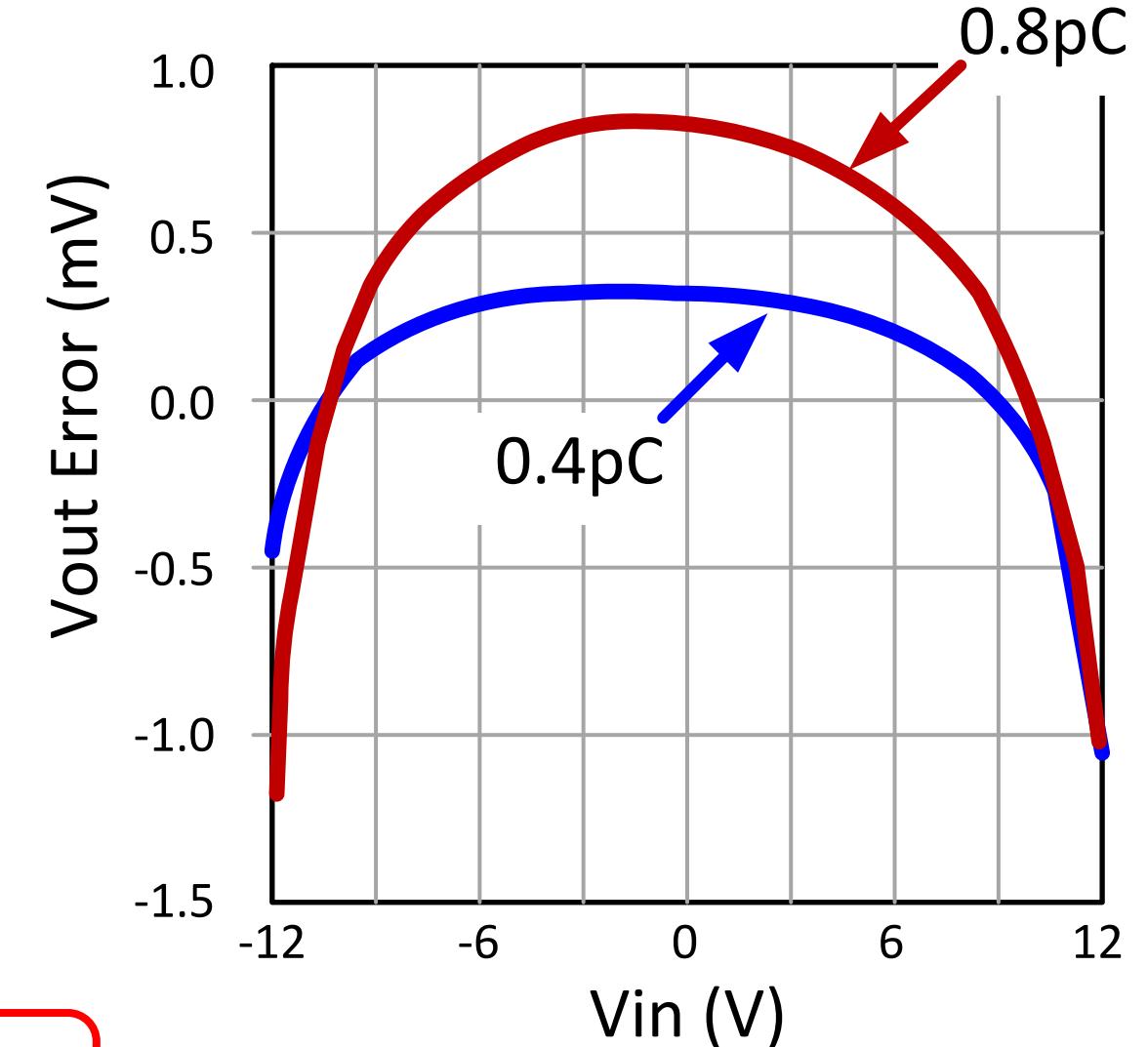
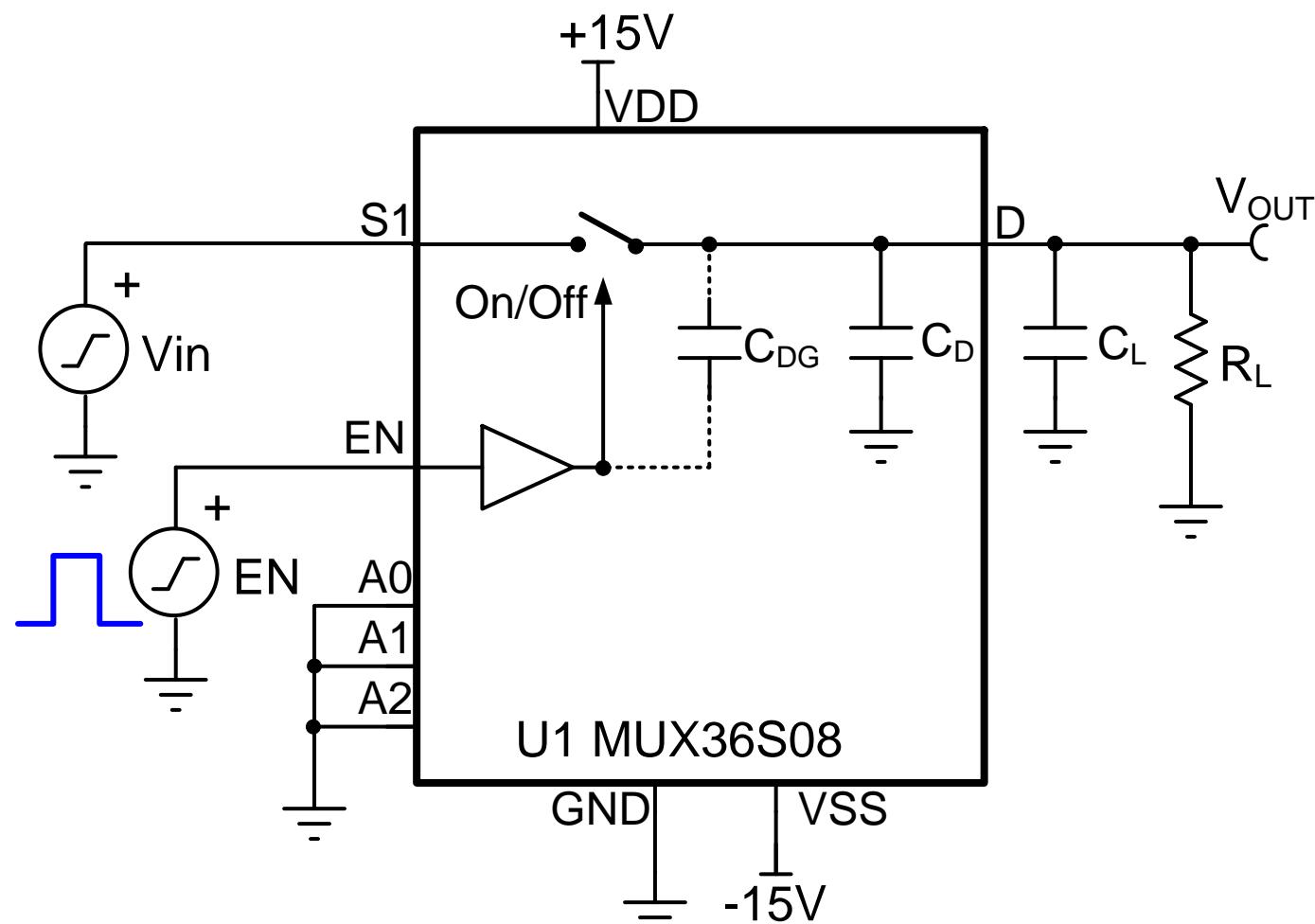
# Charge Injection ( $Q_{INJ}$ )



$$Q_{INJ} = (C_D + C_L) \cdot \Delta V_{out}$$

- **Charge injection Error:** Voltage change introduced at the output of switch when switch is turned ON or OFF
- Larger load capacitance minimizes the effect of charge Injection at the multiplexer output

# Charge Injection Error vs. Input Voltage



$$\text{Error} = Q_{INJ} / C_L$$

# Summary: MUX Leakage Current and Charge Injection

## Leakage Current

- Introduces DC offset Error
- Varies with temperature and can introduces linearity errors too
- Important parameter for high input impedance data acquisition systems

## Charge Injection

- Introduces output voltage error when control logic is switched
- Typically worse on multiplexers with large Con.
- Smaller the load capacitor higher the error introduced due to charge injection
- Important parameter for fast switching systems



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**Thanks for your time!  
Please try the quiz.**



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